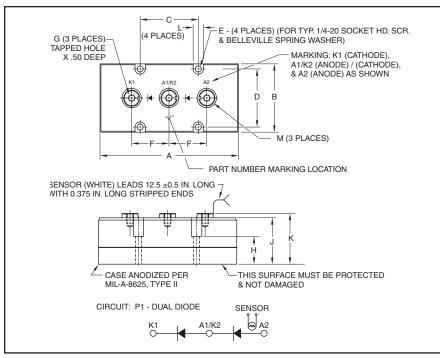


Powerex, Inc., 173 Pavilion Lane, Youngwood, Pennsylvania 15697 (724) 925-7272 www.pwrx.com

Phase Control Dual Diode Module 985 Amperes/Up to 5000 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters	
Α	8.50	215.9	
В	4.33	109.98	
С	3.15	80.01	
D	3.78	96.01	
Е	0.328 Dia.	8.33 Dia.	
F	2.34±0.03	59.4±0.8	
G	7/16-14 UNC-2B		
Н	2.14	54.36	
J	3.15	80.01	
K	3.38 85.		
L	0.56 14.22		
М	1.12	28.45	

All dimensions are 0.02 unless otherwise specified.

Voltage Code: Wxx

Туре	Voltage Code	Voltage Volts
P1ZAA	W36	3600
	W42	4200
	W45	4500
	1	I
	W50	5000

Ordering Information:

Select the complete thirteen digit module part number from the Element, Special and Voltage Tables below.

Example: P1 ZAA DDA 00 W50 is a Dual Diode POW-R-BRIKTM Module with 67mm elements, Rated 985 Ampere, Standard Thermistor and rated at 5000 Volts.

Element Code: DDA

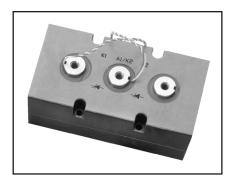
Special Code: 00

00 - Standard Thermistor

XT - No Thermistor

AA-ZZ - Special customer unique specifications.

Note: For detailed application information on thermistor circuit refer to Rectifier/Thyristor Module Data Book, Page 3.



Description:

Powerex Dual Diode POW-R-BRIK™ Modules are designed for medium and high current applications. POW-R-BRIK™ Modules feature an electrically isolated package that simplifies system packaging, installation and cooling. POW-R-BRIK™ Modules utilize Compression Bonded Encapsulation (CBE) mounting and double side cooling of the semiconductor elements. The P1ZAA uses 67mm diodes. Other standard circuit configurations include SCR/SCR, SCR/Diode and Diode/SCR. Additional circuit configurations, e.g. single element, common cathode, common anode, and special element types, e.g. fast switch SCRs, fast recovery diodes are available.

Features:

Αp	plications:
	DC Motor Controls
	Transportation Systems
	Battery Supplies
	Bridge Circuits
	Resistance Welding Controls

☐ Mining Power Centers

03/10 Rev. 1



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P1ZAA POW-R-BRIK Phase Control Dual Diode Module 985 Amperes/Up to 5000 Volts

Absolute Maximum Ratings, $T_j = 25^{\circ}\text{C}$ unless otherwise specified

Ratings	Symbol	P1ZAA	Units
Junction Temperature	Тј	-40 to 150	°C
Storage Temperature	T _{stg}	-40 to 125	°C
Repetitive Peak Forward and Reverse Blocking Voltage	V _{RRM}	Up to 5000	Volts
Non-Repetitive Reverse Blocking Voltage	V _{RSM}	V _{RRM} +100	Volts
RMS Forward Current	IT(RMS)	1320	Amperes
Average Forward Current (180° Conduction, T _C = 80°C)	I _{T(avg)}	985	Amperes
Peak Half-Cycle Surge Current (8.3 ms, 100% V _{RRM} Reapplied)	ITSM	24,000	Amperes
Peak Half-Cycle Surge Current (10.0 ms, 100% V _{RRM} Reapplied)	ITSM	21,800	Amperes
I ² t for Fusing for One Cycle (8.3 ms, 100% V _{RRM} Reapplied)	I ² t	2.40 x 10 ⁶	A ² -sec
I ² t for Fusing for One Cycle (10.0 ms, 100% V _{RRM} Reapplied)	I ² t	2.37 x 10 ⁶	A ² -sec
Maximum Electrical Terminal Mounting Torque	_	30	ft-lbs
Maximum Mounting Bolt Torque	_	12	ft-lbs
Module Weight, Typical	_	19	lbs
		8.6	Kg
Isolation Voltage	V _{ISO}	5000	V _{rms}

Electrical Characteristics, $T_i = 25$ °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Max.	Units
Repetitive Peak Forward and	IDRM/IRRM	T _j = 150°C	150	mA
Reverse Leakage Current				
Peak On-State Voltage	V _{TM}	T _j = 25°C, I _{TM} = 3000A	1.45	Volts
Threshold Voltage, Low-Level	V _{(TO)1}	$T_j = 150$ °C, $I = 15\% I_{T(avg)}$ to $\pi I_{T(avg)}$	0.964	Volts
Slope Resistance, Low-Level	rT1		0.207	$m\Omega$
Threshold Voltage, High-Level	V _{(TO)2}	$T_j = 150$ °C, I = 15% $\pi I_{T(avg)}$ to ITSM	1.77	Volts
Slope Resistance, High-Level	r _{T2}		0.125	$m\Omega$
V _{TM} Coefficients, Low-Level		$T_j = 150^{\circ}C$, $I = 15\% I_{T(avg)} to \pi I_{T(avg)}$	A = 1.983	
			B = -0.254	
			$C = 6.38 \times 10^{-5}$	
			D = 0.02697	

Thermal and Mechanical Characteristics, T_j = 25 °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Max.	Units
Thermal Resistance, Junction to Case	R _{th(j-c)} Q	Per Module, Both Conducting	0.024	°C/W
Thermal Resistance, Junction to Case	R _{th(j-c)} D	Per Diode, Both Conducting	0.048	°C/W
Thermal Resistance,	R _{th(c-s)}	Per Module	0.007	°C/W
Case to Sink (Lubricated)				

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